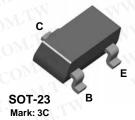


MPS5179







NPN RF Transistor

This device is designed for use in low noise UHF/VHF amplifiers with collector currents in the 100 µA to 30 mA range in common emitter or common base mode of operation, and in low frequency drift, high ouput UHF oscillators. Sourced from Process 40.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	12	V CO
V _{CBO}	Collector-Base Voltage	20	21 100A
V _{EBO}	Emitter-Base Voltage	2.5	V
I _C	Collector Current - Continuous	50	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	.°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	1100Y.COM	Units	
	INN. ICOM. TW	PN/MPS5179	*MMBT5179	
P_D	Total Device Dissipation Derate above 25°C	350 2.8	225 1.8	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

²⁾ These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

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NPN RF Transistor

(continued)

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Electrical Characteristics

TA = 25°C unless otherwise noted

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	Parameter	Test Conditions	Min	Max	Units
OFF CHARA	ACTERISTICS				
V _{CEO(sus)}	Collector-Emitter Sustaining Voltage*	$I_C = 3.0 \text{ mA}, I_B = 0$	12	I.A.	V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 1.0 \mu\text{A}, I_E = 0$	20	TW	V
V _{(BR)EBO} [Emitter-Base Breakdown Voltage	$I_E = 10 \mu\text{A}, I_C = 0$	2.5		V
I _{CBO} (Collector Cutoff Current	V _{CB} = 15 V, I _E = 0 V _{CB} = 15 V, T _A = 150°C	ov.co	0.02 1.0	μA μA

ON CHA	RACTERISTICS				
h _{FE}	DC Current Gain	$I_C = 3.0 \text{ mA}, V_{CE} = 1.0 \text{ V}$	25	250	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$	- 1007	0.4	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$	M. P	1.0	V

SMALL SIGNAL CHARACTERISTICS

f _T	Current Gain - Bandwidth Product	$I_C = 5.0 \text{ mA}, V_{CE} = 6.0 \text{ V},$ f = 100 MHz	900	2000	MHz
C _{cb}	Collector-Base Capacitance	V _{CB} = 10 V, I _E = 0, f = 0.1 to 1.0 MHz	WWW.	1.0	pF
h _{fe}	Small-Signal Current Gain	$I_C = 2.0 \text{ mA}, V_{CE} = 6.0 \text{ V},$ f = 1.0 kHz	25	300	CO_M
rb'C _c	Collector Base Time Constant	$I_C = 2.0 \text{ mA}, V_{CB} = 6.0 \text{ V},$ f = 31.9 MHz	3.0	14	ps
NF	Noise Figure	$I_C = 1.5 \text{ mA}, V_{CE} = 6.0 \text{ V},$ $R_S = 50\Omega, f = 200 \text{ MHz}$	WV	5.0	dB

FUNCTIONAL TEST

FUNCT	IONAL TEST				
G _{pe}	Amplifier Power Gain	$V_{CE} = 6.0 \text{ V}, I_{C} = 5.0 \text{ mA},$ f = 200 MHz	15	WWW.	dB
Po	Power Output	$V_{CB} = 10 \text{ V}, I_{E} = 12 \text{ mA},$ f $\geq 500 \text{ MHz}$	20	WWW	mW

^{*}Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%

Spice Model

NPN (Is=69.28E-18 Xti=3 Eq=1.11 Vaf=100 Bf=282.1 Ne=1.177 Ise=69.28E-18 Ikf=22.03m Xtb=1.5 Br=1.176 Nc=2 lsc=0 lkr=0 Rc=4 Cjc=1.042p Mjc=.2468 Vjc=.75 Fc=.5 Cje=1.52p Mje=.3223 Vje=.75 Tr=1.588n Tf=135.6p ltf=.27 Vtf=10 Xtf=30 Rb=10)

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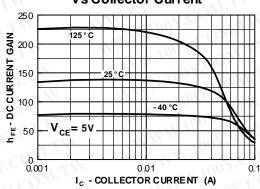
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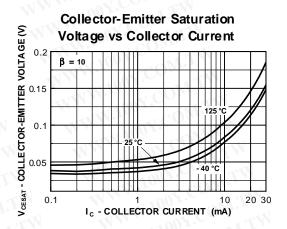
NPN RF Transistor

(continued)

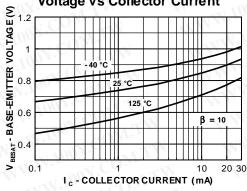
Typical Characteristics

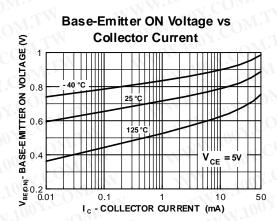




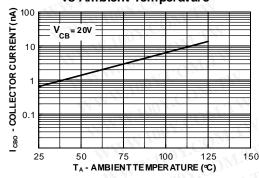


Base-Emitter Saturation Voltage vs Collector Current

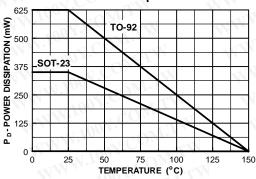




Collector-Cut off Current vs Ambient Temperature







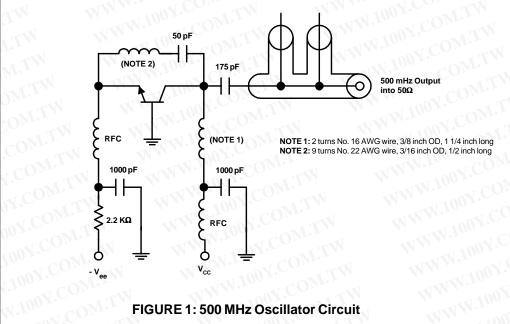
NPN RF Transistor

(continued)

Test Circuit

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FIGURE 1: 500 MHz Oscillator Circuit WWW.100Y.COM.

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WWW.100X

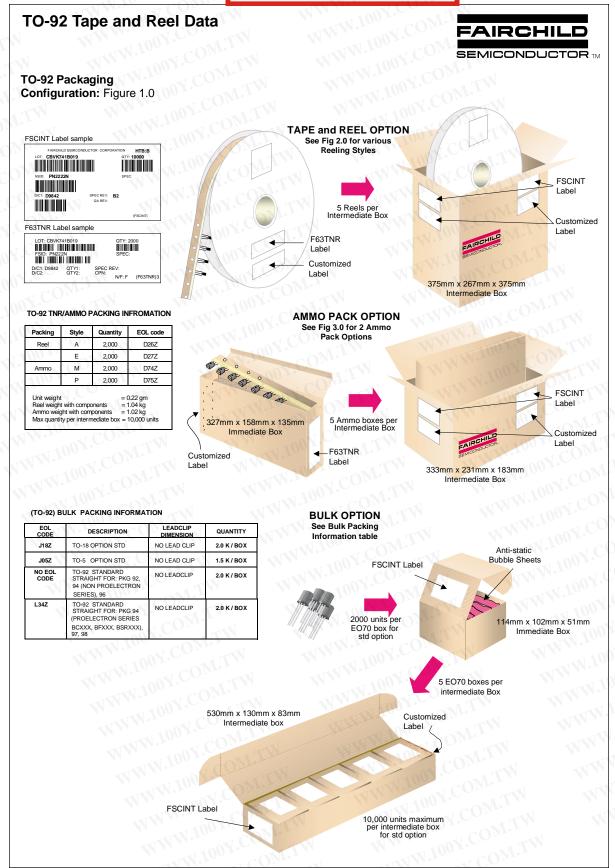
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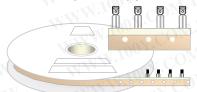
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TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)



Style "A", D26Z, D70Z (s/h)

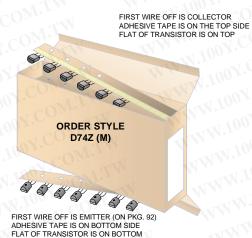
Machine Option "E" (J)

8 8 8 8

Style "E", D27Z, D71Z (s/h)

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TO-92 Radial Ammo Packaging Configuration: Figure 3.0



FIRST WIRE OFF IS EMITTER
ADHESIVE TAPE IS ON THE TOP SIDE
FLAT OF TRANSISTOR IS ON BOTTOM

ORDER STYLE
D75Z (P)

FIRST WIRE OFF IS COLLECTOR (ON PKG. 92)
ADHESIVE TAPE IS ON BOTTOM SIDE

FLAT OF TRANSISTOR IS ON TOP

TAN TOOK COM

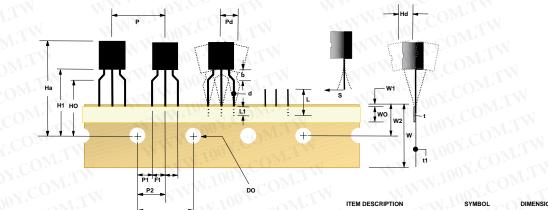
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TO-92 Tape and Reel Data, continued

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TO-92 Tape and Reel Taping Dimension Configuration: Figure 4.0



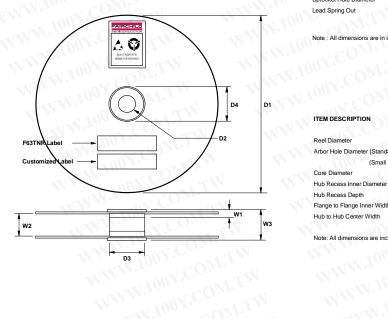
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User Direction of Feed

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TO-92 Reel

Configuration: Figure 5.0



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TIEM DESCRIPTION	SYMBOL	DIMENSION
Base of Package to Lead Bend	, b	0.098 (max)
Component Height	Ha	0.928 (+/- 0.025)
Lead Clinch Height	НО	0.630 (+/- 0.020)
Component Base Height	H1	0.748 (+/- 0.020)
Component Alignment (side/side)	Pd	0.040 (max)
Component Alignment (front/back)	Hd	0.031 (max)
Component Pitch	Р	0.500 (+/- 0.020)
Feed Hole Pitch	PO	0.500 (+/- 0.008)
Hole Center to First Lead	P1	0.150 (+0.009, -0.010)
Hole Center to Component Center	P2	0.247 (+/- 0.007)
Lead Spread	F1/F2	0.104 (+/- 0 .010)
Lead Thickness	d	0.018 (+0.002, -0.003)
Cut Lead Length	L	0.429 (max)
Taped Lead Length	L1	0.209 (+0.051, -0.052)
Taped Lead Thickness	t	0.032 (+/- 0.006)
Carrier Tape Thickness	t1	0.021 (+/- 0.006)
Carrier Tape Width	W	0.708 (+0.020, -0.019)
Hold - down Tape Width	WO	0.236 (+/- 0.012)
Hold - down Tape position	W1	0.035 (max)
Feed Hole Position	W2	0.360 (+/- 0.025)
Sprocket Hole Diameter	DO	0.157 (+0.008, -0.007)
Lead Spring Out	S	0.004 (max)

Note : All dimensions are in inches

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ITEM DESCRIPTION	SYSMBOL	MINIMUM	MAXIMUM	700	
Reel Diameter	D1	13.975	14.025	110	
Arbor Hole Diameter (Standard)	D2	1.160	1.200		
(Small Hole)	D2	0.650	0.700	% []	
Core Diameter	D3	3.100	3.300	NA .	
Hub Recess Inner Diameter	D4	2.700	3.100		
Hub Recess Depth	W1	0.370	0.570	IN	
Flange to Flange Inner Width	W2	1.630	1.690		
Hub to Hub Center Width	W3		2.090		

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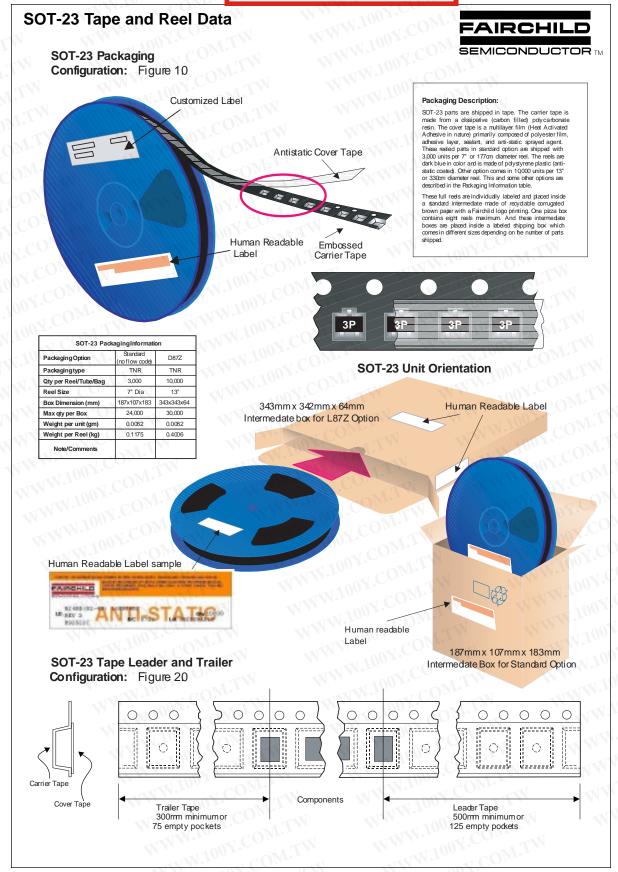
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TO-92 Package Dimensions FAIRCHILD TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 2.0°TYP. TO-92 (92,94,96) 92 94 96 PIN В F В BF 0.76 0.36 D В S 1 D Ε 2 В S С G Ε D Ø0.060 [Ø1.52] 3 G В S С С G 0.010 [0.254] DEEP 勝 特 力 材 料 886-3-5753170 0.48 0.30 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 5.0°TYP. Http://www. 100y. com. tw

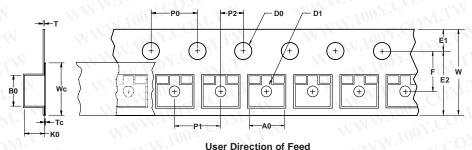


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SOT-23 Tape and Reel Data, continued

SOT-23 Embossed Carrier Tape

Configuration: Figure 3.0



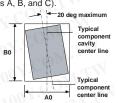
Ohr	< \$1		- 1 TV	14	05/	JOS.	-011		- 41			V.C		
COM.	- 1		VV .	WW.1	Di	mension	s are in	millimete	r		N.Too	V.C	D_{Mr}	
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Ţ	Wc	
SOT-23 (8mm)	3.15 +/-0.10	2.77	8.0 +/-0.3	1.55 +/-0.05	1.125 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.30 +/-0.10	0.228 +/-0.013	5.2 +/-0.3	0.0

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)

Component Rotation



Sketch B (Top View)
Component Rotation

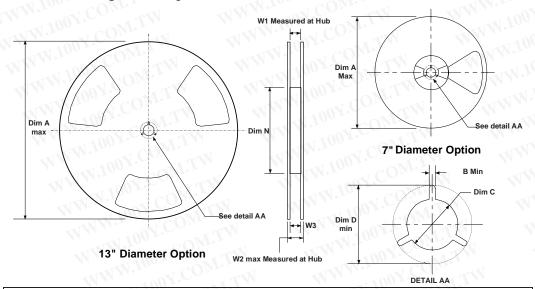


Тс

Sketch C (Top View)

Component lateral movement

SOT-23 Reel Configuration: Figure 4.0



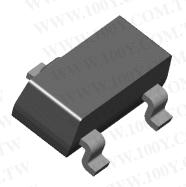
Dimensions are in inches and millimeters									
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9

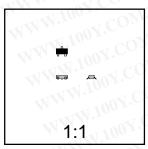
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SOT-23 Package Dimensions



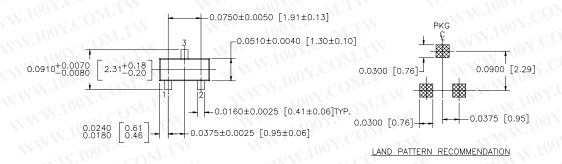
SOT-23 (FS PKG Code 49)

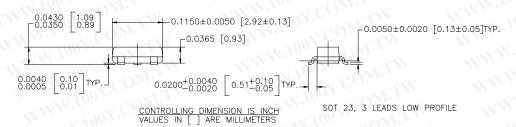




Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.0082





NOTE: UNLESS OTHERWISE SPECIFIED

- STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

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- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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